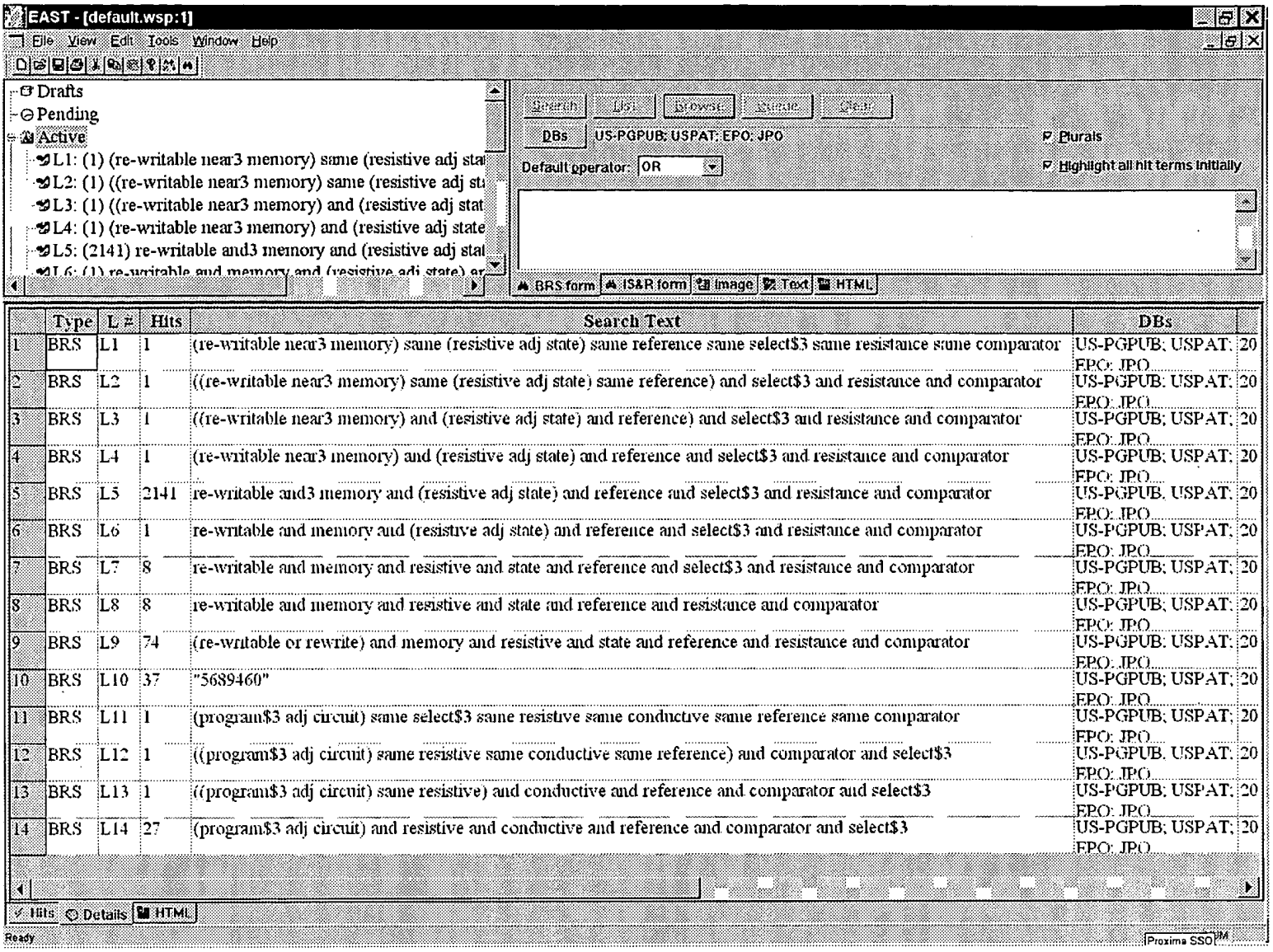

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	1	(re-writable near3 memory) same (resistive adj state) same reference same select$3 same resistance same comparator	US-PGPUB; USPAT; EPO; JPO 20
2	BRS	L2	1	((re-writable near3 memory) same (resistive adj state) same reference) and select$3 and resistance and comparator	US-PGPUB; USPAT; EPO; JPO 20
3	BRS	L3	1	((re-writable near3 memory) and (resistive adj state) and reference) and select$3 and resistance and comparator	US-PGPUB; USPAT; EPO; JPO 20
4	BRS	L4	1	(re-writable near3 memory) and (resistive adj state) and reference and select$3 and resistance and comparator	US-PGPUB; USPAT; EPO; JPO 20
5	BRS	L5	2141	re-writable and3 memory and (resistive adj state) and reference and select$3 and resistance and comparator	US-PGPUB; USPAT; EPO; JPO 20
6	BRS	L6	1	re-writable and memory and (resistive adj state) and reference and select$3 and resistance and comparator	US-PGPUB; USPAT; EPO; JPO 20
7	BRS	L7	8	re-writable and memory and resistive and state and reference and select$3 and resistance and comparator	US-PGPUB; USPAT; EPO; JPO 20
8	BRS	L8	8	re-writable and memory and resistive and state and reference and resistance and comparator	US-PGPUB; USPAT; EPO; JPO 20
9	BRS	L9	74	(re-writable or rewrite) and memory and resistive and state and reference and resistance and comparator	US-PGPUB; USPAT; EPO; JPO 20
10	BRS	L10	37	"5689460"	US-PGPUB; USPAT; EPO; JPO 20
11	BRS	L11	1	(program$3 adj circuit) same select$3 same resistive same conductive same reference same comparator	US-PGPUB; USPAT; EPO; JPO 20
12	BRS	L12	1	((program$3 adj circuit) same resistive same conductive same reference) and comparator and select$3	US-PGPUB; USPAT; EPO; JPO 20
13	BRS	L13	1	((program$3 adj circuit) same resistive) and conductive and reference and comparator and select$3	US-PGPUB; USPAT; EPO; JPO 20
14	BRS	L14	27	(program$3 adj circuit) and resistive and conductive and reference and comparator and select$3	US-PGPUB; USPAT; EPO; JPO 20